## Precision, $40 \mathrm{~V}, \pm 70 \mathrm{nV} /{ }^{\circ} \mathrm{C}$, Rail-to-Rail Input and Output Op Amp with DigiTrim

## FEATURES

- Low offset voltage drift: $\pm 70 \mathrm{nV} /{ }^{\circ} \mathrm{C}$ typical
- Low offset voltage: $\pm 5 \mu \mathrm{~V}$ typical, $\pm 20 \mu \mathrm{~V}$ maximum
- Low voltage noise: $1 \mu \mathrm{~V}$ p-p from 0.1 Hz to 10 Hz typical
- Low voltage noise density: $5 \mathrm{nV} / \mathrm{WHz}$ typical at $\mathrm{f}=1 \mathrm{kHz}$
- High common-mode rejection: 140 dB typical
- Low input bias current: $\pm 10 \mathrm{pA}$ maximum
- Wide gain bandwidth product: 10.4 MHz typical
- High slew rate: $19 \mathrm{~V} / \mu \mathrm{s}$ typical
- Low THD: - 134 dB at $\mathrm{f}=1 \mathrm{kHz}$
- Low quiescent supply current: 1.45 mA per amplifier typical
- Wide supply voltage operation: 6 V to $40 \mathrm{~V}, \pm 3 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$
- Integrated EMI filter
- Multiplexer compatible inputs
- Rail-to-rail high impedance inputs: differential and commonmode
- Fast settling time
- Rail-to-rail output
- No phase reversal
- Heavy capacitive load drive capability: 1 nF
- Wide specified temperature range: $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
- Available in 8 -lead standard small outline package (SOIC_N)


## APPLICATIONS

- Electronic test and measurement
- Data acquisition systems
- Automated test equipment
- Medical instruments
- Multiplexed input signal chains
- Precision current measurement
- Photodiode amplifiers


## GENERAL DESCRIPTION

The ADA4510-2 ${ }^{1}$ is a dual-channel, 40 V , high precision, low input bias current, low offset voltage, low offset voltage drift, low noise, rail-to-rail input and output operational amplifier that can be used at any point of the signal chain, including sensing, conditioning, and output drive. Through the use of Analog Devices, Inc., proprietary DigiTrim ${ }^{\text {TM }}$ technique, the ADA4510-2 achieves best-in-class low offset drift ( $\pm 70 \mathrm{nV} /{ }^{\circ} \mathrm{C}$ typical, $\pm 500 \mathrm{nV} /{ }^{\circ} \mathrm{C}$ maximum) and low offset voltage ( $\pm 5 \mu \mathrm{~V}$ typical, $\pm 20 \mu \mathrm{~V}$ maximum), simplifying temperature calibrations in precision designs.
The ADA4510-2 delivers excellent DC precision and outstanding AC performance, making it a top choice for a wide variety of signal chain applications. By integrating a robust mux-compatible architecture, the ADA4510-2 effectively solves common system distortion and settling problems and provides the superior accuracy required in multiplexed multichannel precision signal chains. The ADA4510-2 is specified from $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ and $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ and is available in an 8 -lead, SOIC_N.


Figure 1. Ultralow Offset Voltage Drift for Precision Design

## TYPICAL APPLICATION CIRCUIT



Figure 2. Multiplexed Data Acquisition Signal Chain
1 Protected by U.S. patent number $11,329,612$; other patents pending.

Rev. A

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## REVISION HISTORY

10/2023—Rev. 0 to Rev. A
Changes to Data Sheet Title1
Changes to Features Section ..... 1
Changes to General Description Section ..... 1
Changes to Offset Voltage Drift ( $\Delta \mathrm{V}_{\mathrm{OS}} / \Delta \mathrm{T}$ ) Parameter, Table 1 ..... 4
Changes to Figure 65 ..... 20
Change to Design Example Section. ..... 24
7/2023—Revision 0: Initial Version

## COMPANION PRODUCTS

- ADC: AD4695/AD4696, AD4697/AD4698, AD4002/AD4006/ AD4010, AD4000/AD4004/AD4008
- ADC Drivers: ADA4945-1, LTC6363, AD8475
- Voltage References: LTC6655, ADR4525
- Power: LT3032, ADP5070, LT3093, LT3042


## SPECIFICATIONS

## ELECTRICAL SPECIFICATIONS FOR $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \mathbf{T O}+85^{\circ} \mathrm{C}$

Supply voltage $\left(\mathrm{V}_{\mathrm{SY}}\right)=(\mathrm{V}+)-(\mathrm{V}-)= \pm 3 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$, common-mode voltage $\left(\mathrm{V}_{\mathrm{CM}}\right)=0 \mathrm{~V}$, load resistor $\left(\mathrm{R}_{\mathrm{L}}\right)=10 \mathrm{k} \Omega$ to midsupply, unless otherwise noted.

Table 1. Electrical Specifications for $T_{A}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS |  |  |  |  |  |
| Offset Voltage (V $\mathrm{V}_{\text {S }}$ ) | $V_{C M}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 5$ | $\pm 20$ | $\mu \mathrm{V}$ |
|  | $0^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 40$ | $\mu \mathrm{V}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 50$ | $\mu \mathrm{V}$ |
|  | $\mathrm{V}_{C M}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 10$ | $\pm 40$ | $\mu \mathrm{V}$ |
|  | $0^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 60$ | $\mu \mathrm{V}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 120$ | $\mu \mathrm{V}$ |
|  | $V_{C M}=(\mathrm{V}-)-0.15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 8$ | $\pm 35$ | $\mu \mathrm{V}$ |
|  | $0^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 90$ | $\mu \mathrm{V}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 110$ | $\mu \mathrm{V}$ |
| Offset Voltage Drift ( $\Delta \mathrm{V}_{0 S} / \Delta T$ ) | $V_{C M}=0 \mathrm{~V}$ |  |  |  |  |
|  | $0^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  | $\pm 70$ | $\pm 500$ | $n \mathrm{~V} /{ }^{\circ} \mathrm{C}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  | $\pm 0.12$ | $\pm 0.5$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
|  | $V_{\text {CM }}=(\mathrm{V}+)^{-1.5 \mathrm{~V}}$ |  |  |  |  |
|  | $0^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  | $\pm 0.1$ | $\pm 0.7$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  | $\pm 0.15$ | $\pm 1$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Input Bias Current ( $\mathrm{I}_{\mathrm{B}}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 2.5$ | $\pm 10$ | pA |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 0.8$ | nA |
| Input Offset Current (los) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 0.5$ | $\pm 5$ | pA |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{A}<+85^{\circ} \mathrm{C}$ |  |  | $\pm 0.15$ | nA |
| Common-Mode Rejection Ratio (CMRR) | Guaranteed by CMRR | (V-) - 0.15 |  | V+ | V |
|  | (V-) - $0.15 \mathrm{~V}<\mathrm{V}_{C M}<\left(\mathrm{V}+\right.$ ) $-3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 121 | 140 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | 118 |  |  | dB |
|  | $(\mathrm{V}-)-0.15 \mathrm{~V}<\mathrm{V}_{\mathrm{CM}}<\mathrm{V}+, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 100 | 112 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | 100 |  |  | dB |
| Open-Loop Voltage Gain ( $\mathrm{AVOL}^{\text {) }}$ | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega,(\mathrm{V}-)+0.3 \mathrm{~V}<\mathrm{V}_{\text {OUT }}<(\mathrm{V}+)-0.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 126 | 140 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | 124 |  |  | dB |
|  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega,(\mathrm{V}-)+0.9 \mathrm{~V}<\mathrm{V}_{\text {OUT }}<(\mathrm{V}+)-0.9 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 121 | 134 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | 120 |  |  | dB |
| Input Capacitance |  |  |  |  |  |
| Differential Mode ( $\mathrm{C}_{\text {INDM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 20 |  | pF |
| Common Mode ( $\mathrm{C}_{\text {INCM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{S Y}= \pm 5 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$ |  | 2 |  | pF |
| Input Resistance |  |  |  |  |  |
| Differential Mode ( $\mathrm{R}_{\text {INDM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 1 |  | T $\Omega$ |
| Common Mode ( $\mathrm{R}_{\text {INCM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10 |  | T $\Omega$ |
| NOISE PERFORMANCE |  |  |  |  |  |
| Voltage Noise ( $\mathrm{e}_{\mathrm{n} p-\mathrm{p}}$ ) | 0.1 Hz to $10 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 1 |  | $\mu \vee p-p$ |
|  | 0.1 Hz to $10 \mathrm{~Hz}, \mathrm{~V}_{\mathrm{CM}}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 2.7 |  | $\mu \vee p-p$ |
| Voltage Noise Density ( $\mathrm{e}_{\mathrm{n}}$ ) | $f=100 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 8 |  | $\mathrm{nV} / \mathrm{NHz}$ |
|  | $\mathrm{f}=1 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 5 |  | $\mathrm{nV} / \mathrm{Hzz}$ |
|  | $\mathrm{f}=100 \mathrm{~Hz}, \mathrm{~V}_{\text {CM }}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 20 |  | $\mathrm{nV} / \mathrm{HHz}$ |
|  | $\mathrm{f}=1 \mathrm{kHz}, \mathrm{V}_{\text {CM }}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10 |  | $\mathrm{nV} / \mathrm{HHz}$ |
| Current Noise Density ( $\mathrm{l}_{\mathrm{n}}$ ) | $\mathrm{f}=10 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 4 |  | fA/ $/ \mathrm{Hz}$ |

## SPECIFICATIONS

Table 1. Electrical Specifications for $T_{A}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ (Continued)

| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |
| Output Swing High ( $\mathrm{V}_{\mathrm{OH}}$ ) | ( (V+)- $\mathrm{V}_{\text {OUT }}$ ) |  |  |  |  |
|  | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 100 | 116 | mV |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | 160 | mV |
|  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 430 | 473 | mV |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | 655 | mV |
| Output Swing Low (VOL) | ( $\mathrm{V}_{\text {OUT }}$ - (V-) $)$ |  |  |  |  |
|  | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 73 | 85 | mV |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | 120 | mV |
|  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 310 | 342 | mV |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | 487 | mV |
| Output Current (lout) | $\left(\mathrm{V}_{\text {OH, }}, \mathrm{V}_{\text {OL }}\right)<1 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 22$ |  | mA |
| Short-Circuit Current (lsc) <br> Closed-Loop Output Impedance (Zout) | Sourcing/sinking, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 55/70 |  | mA |
|  | $\mathrm{f}=1 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  |  |
|  | Gain $=1$ |  | 19 |  | $m \Omega$ |
|  | Gain = 10 |  | 190 |  | $\mathrm{m} \Omega$ |
|  | Gain $=100$ |  | 1.9 |  | $\Omega$ |
| Open-Loop Output Impedance ( $\mathrm{Z}_{0}$ ) | $\mathrm{f}=1 \mathrm{kHz}$ to $1 \mathrm{MHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 190 |  | $\Omega$ |
| POWER SUPPLY |  |  |  |  |  |
| $\mathrm{V}_{S Y}((\mathrm{~V}+)-(\mathrm{V}-))$ | Guaranteed by PSRR | 6 |  | 40 | V |
| Power Supply Rejection Ratio (PSRR) | $\mathrm{V}_{S Y}= \pm 3 \mathrm{~V}$ to $\pm 20 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 121 | 140 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | 117 |  |  | dB |
| Supply Current per Amplifier (ISY) | IOUT $=0 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 1.45 | 1.55 | mA |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ |  |  | 1.85 | mA |
| DYNAMIC PERFORMANCE |  |  |  |  |  |
| Slew Rate | $V_{\text {OUT }}= \pm 5 \mathrm{~V}$, gain $=+1,10 \%$ to $90 \%, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 19 |  | V/us |
| Gain Bandwidth Product (GBP) | $\mathrm{f}=100 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10.4 |  | MHz |
| -3 dB Bandwidth <br> Settling Time ( $\mathrm{t}_{\mathrm{s}}$ ) | Gain $=1, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 13.5 |  | MHz |
|  | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  |  |
| Output Overload Recovery Time Total Harmonic Distortion (THD) | To 0.01\% |  |  |  |  |
|  | Gain $=-1, \mathrm{~V}_{\text {OUT }}=5 \mathrm{~V}$ step |  | 1.9 |  | $\mu \mathrm{S}$ |
|  | Gain $=-1, \mathrm{~V}_{\text {OUT }}=10 \mathrm{~V}$ step |  | 2.2 |  | $\mu \mathrm{s}$ |
|  | To 0.001\% |  |  |  |  |
|  | Gain $=-1, \mathrm{~V}_{\text {OUT }}=5 \mathrm{~V}$ step |  | 3.1 |  | $\mu \mathrm{s}$ |
|  | Gain $=-1, \mathrm{~V}_{\text {OUT }}=10 \mathrm{~V}$ step |  | 3.5 |  | $\mu \mathrm{S}$ |
|  | Gain $=-10, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, positive/negative |  | 300/100 |  | ns |
|  | $\mathrm{V}_{\text {OUT }}=10 \mathrm{~V}$ p-p, gain $=1, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  |  |
|  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 0.00002 |  | \% |
|  | $\mathrm{f}=1 \mathrm{kHz}$ |  | -134 |  | dB |
|  | $\mathrm{f}=50 \mathrm{kHz}$ |  | 0.0045 |  | \% |
|  | $\mathrm{f}=50 \mathrm{kHz}$ |  | -87 |  | dB |
| ELECTROMAGNETIC INTERFERENCE REJECTION RATIO (EMIRR) | EMIRR $=20 \times \log _{10}\left(\Delta V_{1 N} / \Delta V_{\text {OS }}\right), \Delta V_{\text {IN }}=200 \mathrm{mV}$ p-p, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  |  |
|  | $\mathrm{f}=1000 \mathrm{MHz}$ |  | 71 |  | dB |
|  | $\mathrm{f}=2400 \mathrm{MHz}$ |  | 81 |  | dB |
| CROSSTALK | $\mathrm{V}_{\text {IN }}=4 \mathrm{~V}$ p-p, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  |  |
|  | DC |  | 165 |  | dB |
|  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 164 |  | dB |
|  | $\mathrm{f}=100 \mathrm{kHz}$ |  | 130 |  | dB |

## SPECIFICATIONS

## ELECTRICAL SPECIFICATIONS FOR $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}{ }^{\circ} \mathrm{C} \mathbf{T O}+125^{\circ} \mathrm{C}$

Supply voltage $\left(\mathrm{V}_{\mathrm{SY}}\right)=(\mathrm{V}+)-(\mathrm{V}-)= \pm 3 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$, common-mode voltage $\left(\mathrm{V}_{\mathrm{CM}}\right)=0 \mathrm{~V}$, load resistor $\left(\mathrm{R}_{\mathrm{L}}\right)=10 \mathrm{k} \Omega$ to midsupply, unless otherwise noted.

Table 2. Electrical Specifications for $T_{A}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$

| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS |  |  |  |  |  |
| Offset Voltage (V $\mathrm{VSS}^{\text {) }}$ | $\mathrm{V}_{\text {CM }}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 5$ | $\pm 20$ | $\mu \mathrm{V}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  |  | $\pm 100$ | $\mu \mathrm{V}$ |
|  | $\mathrm{V}_{\text {CM }}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 10$ | $\pm 40$ | $\mu \mathrm{V}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  |  | $\pm 380$ | $\mu \mathrm{V}$ |
|  | $V_{C M}=\mathrm{V}-, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 9$ | $\pm 35$ | $\mu \mathrm{V}$ |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  |  | $\pm 160$ | $\mu \mathrm{V}$ |
| Offset Voltage Drift ( $\Delta \mathrm{V}_{0 \mathrm{~S}} / \Delta \mathrm{T}$ ) | $V_{C M}=0 \mathrm{~V}$ |  |  |  |  |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | $\pm 0.12$ | $\pm 0.7$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
|  | $V_{C M}=(\mathrm{V}+)^{-1.5 V}$ |  |  |  |  |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | $\pm 0.5$ | $\pm 2.4$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Input Bias Current ( $\mathrm{I}_{\mathrm{B}}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 2.5$ | $\pm 10$ | pA |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  |  | $\pm 18$ | nA |
| Input Offset Current (los) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\pm 0.5$ | $\pm 5$ | pA |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  |  | $\pm 5$ | nA |
| Common-Mode Rejection Ratio (CMRR) | Guaranteed by CMRR | V- |  | V+ | V |
|  | $\mathrm{V}-<\mathrm{V}_{\text {CM }}<(\mathrm{V}+)-3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 121 | 140 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | 109 |  |  | dB |
|  | $\mathrm{V}-<\mathrm{V}_{C M}<\mathrm{V}+\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 100 | 112 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | 95 |  |  | dB |
| Open-Loop Voltage Gain (Avol) | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega,(\mathrm{V}-)+0.3 \mathrm{~V}<\mathrm{V}_{\text {OUT }}<(\mathrm{V}+)-0.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 126 | 140 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | 112 |  |  | dB |
|  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega,(\mathrm{V}-)+0.9 \mathrm{~V}<\mathrm{V}_{\text {OUT }}<(\mathrm{V}+)-0.9 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 121 | 134 |  | dB |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | 106 |  |  | dB |
| Input Capacitance |  |  |  |  |  |
| Differential Mode ( $\mathrm{C}_{\text {INDM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 20 |  | pF |
| Common Mode ( $\mathrm{C}_{\text {INCM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SY}}= \pm 5 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$ |  | 2 |  | pF |
| Input Resistance |  |  |  |  |  |
| Differential Mode ( $\mathrm{R}_{\text {INDM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 1 |  | T $\Omega$ |
| Common Mode ( $\mathrm{R}_{\text {INCM }}$ ) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10 |  | T $\Omega$ |
| NOISE PERFORMANCE |  |  |  |  |  |
| Voltage Noise ( $\mathrm{e}_{\mathrm{n}}^{\mathrm{p}-\mathrm{p}}$ ) | 0.1 Hz to $10 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 1 |  | $\mu \mathrm{V}$ p-p |
|  | 0.1 Hz to $10 \mathrm{~Hz}, \mathrm{~V}_{\mathrm{CM}}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 2.7 |  | $\mu \mathrm{V}$-p |
| Voltage Noise Density ( $\mathrm{e}_{\mathrm{n}}$ ) | $\mathrm{f}=100 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 8 |  | $\mathrm{nV} / \mathrm{NHz}$ |
|  | $\mathrm{f}=1 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 5 |  | $\mathrm{nV} / \mathrm{WHz}$ |
|  | $\mathrm{f}=100 \mathrm{~Hz}, \mathrm{~V}_{\text {CM }}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 20 |  | $\mathrm{nV} / \mathrm{WHz}$ |
|  | $\mathrm{f}=1 \mathrm{kHz}, \mathrm{V}_{\mathrm{CM}}=(\mathrm{V}+)-1.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 10 |  | $\mathrm{nV} / \mathrm{VHz}$ |
| Current Noise Density ( $\mathrm{I}_{\mathrm{n}}$ ) | $\mathrm{f}=10 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 4 |  | $\mathrm{fA} / \mathrm{NHz}$ |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |
| Output Swing High (VOH) | ( (V+)- $\mathrm{V}_{\text {OUT }}$ ) |  |  |  |  |
|  | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 100 | 116 | mV |
|  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  |  | 187 | mV |
|  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 430 | 473 | mV |

## SPECIFICATIONS

Table 2. Electrical Specifications for $T_{A}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ (Continued)

| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Output Swing Low (VOL) <br> Output Current (lout) <br> Short-Circuit Current (ISC) <br> Closed-Loop Output Impedance (Zout) <br> Open-Loop Output Impedance $\left(Z_{0}\right)$ | $\begin{aligned} & -40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C} \\ & \left(\mathrm{~V}_{\text {OUT }}-(\mathrm{V}-)\right) \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C} \\ & \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C} \\ & \left(\mathrm{~V}_{\mathrm{OH}}, \mathrm{~V}_{\mathrm{OL}}\right)<1 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \text { Sourcing/sinking, } T_{A}=25^{\circ} \mathrm{C} \\ & \mathrm{f}=1 \mathrm{kHz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \text { Gain }=1 \\ & \text { Gain }=10 \\ & \text { Gain }=100 \\ & \mathrm{f}=1 \mathrm{kHz} \text { to } 1 \mathrm{MHz}, T_{A}=25^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 73 \\ & 310 \\ & \pm 22 \\ & 55 / 70 \\ & \\ & 19 \\ & 190 \\ & 1.9 \\ & 190 \end{aligned}$ | $\begin{aligned} & 765 \\ & \\ & 85 \\ & 142 \\ & 342 \\ & 573 \end{aligned}$ | $\begin{aligned} & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \\ & \mathrm{~m} \Omega \\ & \mathrm{~m} \Omega \\ & \Omega \\ & \Omega \end{aligned}$ |
| POWER SUPPLY $V_{S Y}((V+)-(V-))$ <br> Power Supply Rejection Ratio (PSRR) <br> Supply Current per Amplifier ( ${ }_{\text {SY }}$ ) | Guaranteed by PSRR $\begin{aligned} & V_{S Y}= \pm 3 \mathrm{~V} \text { to } \pm 20 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C} \\ & \text { IOUT }=0 \mathrm{~mA}, T_{A}=25^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C}<\mathrm{T}_{A}<+125^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & 6 \\ & 121 \\ & 116 \end{aligned}$ | $140$ $1.45$ | 40 $\begin{aligned} & 1.55 \\ & 2 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| DYNAMIC PERFORMANCE <br> Slew Rate <br> Gain Bandwidth Product (GBP) -3 dB Bandwidth Settling Time ( $\mathrm{t}_{\mathrm{s}}$ ) <br> Output Overload Recovery Time Total Harmonic Distortion (THD) | $\begin{aligned} & V_{\text {OUT }}= \pm 5 \mathrm{~V}, \text { gain }=1,10 \% \text { to } 90 \%, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \mathrm{f}=100 \mathrm{kHz}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \text { Gain }=1, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \text { To } 0.01 \% \\ & \text { Gain }=-1, \mathrm{~V}_{\text {OUT }}=5 \mathrm{~V} \text { step } \\ & \text { Gain }=-1, \mathrm{~V}_{\text {OUT }}=10 \mathrm{~V} \text { step } \\ & \text { To } 0.001 \% \\ & \text { Gain }=-1, \mathrm{~V}_{\text {OUT }}=5 \mathrm{~V} \text { step } \\ & \text { Gain }=-1, \mathrm{~V}_{\text {OUT }}=10 \mathrm{~V} \text { step } \\ & \text { Gain }=-10, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \text { positive } / \text { negative } \\ & \mathrm{V}_{\text {OUT }}=10 \mathrm{~V} \text { p-p, gain }=1, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \mathrm{f}=1 \mathrm{kHz} \\ & \mathrm{f}=1 \mathrm{kHz} \\ & \mathrm{f}=50 \mathrm{kHz} \\ & \mathrm{f}=50 \mathrm{kHz} \end{aligned}$ |  | 19 <br> 10.4 <br> 13.5 <br> 1.9 <br> 2.2 <br> 3.1 <br> 3.5 <br> 300/100 <br> 0.00002 <br> -134 <br> 0.00445 <br> -87 |  | V/us <br> MHz <br> MHz <br> US <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{S}$ <br> $\mu \mathrm{S}$ <br> ns <br> \% <br> dB <br> \% <br> dB |
| ELECTROMAGNETIC INTERFERENCE REJECTION RATIO (EMIRR) | $\begin{aligned} & \text { EMIRR }=20 \times \log _{10}\left(\Delta V_{I N} / \Delta V_{O S}\right), \Delta V_{I N}=200 \mathrm{mV} p-p, T_{A}=25^{\circ} \mathrm{C} \\ & f=1000 \mathrm{MHz} \\ & f=2400 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 71 \\ & 81 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| CROSSTALK | $\begin{aligned} & V_{\mathbb{N}}=4 \mathrm{Vp}-\mathrm{p}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & D C \\ & f=1 \mathrm{kHz} \\ & \mathrm{f}=100 \mathrm{kHz} \end{aligned}$ |  | $\begin{aligned} & 165 \\ & 164 \\ & 130 \\ & \hline \end{aligned}$ |  | $\begin{array}{\|l\|} \hline \mathrm{dB} \\ \mathrm{~dB} \\ \mathrm{~dB} \\ \hline \end{array}$ |

## ABSOLUTE MAXIMUM RATINGS

Table 3. Absolute Maximum Ratings

| Parameter | Rating |
| :---: | :---: |
| $\mathrm{V}_{\text {SY }}((\mathrm{V}+)-(\mathrm{V}-))$ | -0.3 V to +45 V |
| Input $\mathrm{V}_{\mathrm{CM}}$ |  |
| (+IN A, -IN A, +IN B, -IN B) to V- | -0.3 V to +45 V |
|  | +0.3V to -45 V |
| Differential Input Voltage |  |
| +IN A to -IN A, +IN B to -IN B | $\pm 45 \mathrm{~V}$ |
| Input Current | $\pm 10 \mathrm{~mA}$ |
| Output Short-Circuit Duration ${ }^{1}$ | Thermally limited |
| Temperature Range |  |
| Storage | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Operating | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| TJ | $150^{\circ} \mathrm{C}$ |
| Lead (soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{C}}$ | $260^{\circ} \mathrm{C}$ |

${ }^{1}$ A heatsink may be required to keep the $T_{j}$ below the absolute maximum rating when the output is shorted indefinitely.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.
$\theta_{\mathrm{JA}}$ is the natural convection junction-to-ambient thermal resistance measured in a one cubic foot sealed enclosure.
$\theta_{\mathrm{Jc}}$ is the junction-to-case thermal resistance.

## Table 4. Thermal Resistance

| Package Type | $\theta_{\mathrm{JA}}$ | $\theta_{\mathrm{JC}}$ | Unit |
| :--- | :--- | :--- | :--- |
| $R$ R-8 | 108.5 | 34.12 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD-sensitive devices in an ESD-protected area only.

Human body model (HBM) per ANSI/ESDA/JEDEC JS-001-2017.
Field induced charged-device model (FICDM) per ANSI/ESDA/JEDEC JS-002-2018.

ESD Ratings for ADA4510-2
Table 5. ADA4510-2, 8-Lead SOIC_N

| ESD Model | Withstand Threshold (V) | Class |
| :--- | :--- | :--- |
| HBM | $\pm 1000$ | 1 C |
| FICDM | $\pm 400$ | C1 |

## ESD CAUTION

|  | ESD (electrostatic discharge) sensitive device. Charged devi- <br> ces and circuit boards can discharge without detection. Although <br> this product features patented or proprietary protection circuitry, <br> damage may occur on devices subjected to high energy ESD. <br> Therefore, proper ESD precautions should be taken to avoid <br> performance degradation or loss of functionality. |
| :---: | :---: |

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



Figure 3. Pin Configuration

Table 6. Pin Function Descriptions, 8-Lead SOIC

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | OUT A | Output, Channel A. |
| 2 | - IN A | Inverting Input, Channel A. |
| 3 | +IN A | Noninverting Input, Channel A. |
| 4 | V- | Negative Supply Voltage. |
| 5 | +IN B | Noninverting Input, Channel B. |
| 6 | $-I N$ B | Inverting Input, Channel B. |
| 7 | OUT B | Output, Channel B. |
| 8 | V+ | Positive Supply Voltage. |

## TYPICAL PERFORMANCE CHARACTERISTICS

$V_{S Y}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ to midsupply, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.


Figure 4. VOS Distribution at $25^{\circ} \mathrm{C}$


Figure 5. VOS Distribution at $-40^{\circ} \mathrm{C}$


Figure 6. Input Offset Voltage Drift ( $\mathrm{TCV}_{\text {OS }}$ ) Distribution from $0^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$


Figure 7. Vos Distribution at $85^{\circ} \mathrm{C}$


Figure 8. $V_{O S}$ Distribution at $125^{\circ} \mathrm{C}$


Figure 9. $\mathrm{TCV}_{0 S}$ Distribution from $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 10. Vos vs. Temperature


Figure 11. $V_{0 S}$ vs. $V_{C M}$


Figure 12. $V_{O S}$ vs. $V_{S Y}$


Figure 13. $V_{O S}$ vs. $V_{C M}$, Four Temperatures


Figure 14. $V_{O S}$ vs. $V_{C M}, H i g h V_{C M}$ Operation


Figure 15. Vos vs. Vout

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 16. $I_{B}$ Distribution at $25^{\circ} \mathrm{C}$


Figure 17. $I_{B}$ Distribution at $-40^{\circ} \mathrm{C}$


Figure 18. $I_{B}$ Distribution at $85^{\circ} \mathrm{C}$


Figure 19. IOS Distribution at $25^{\circ} \mathrm{C}$


Figure 20. Ios Distribution at $-40^{\circ} \mathrm{C}$


Figure 21. $I_{O S}$ Distribution at $85^{\circ} \mathrm{C}$

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 22. $I_{B}$ vs. $V_{C M}$


Figure 23. $I_{B}$ vs. Temperature


Figure 24. $V_{\text {DROPOUT }}\left(\left(V^{+}\right)-V_{\text {OUT }}\right)$ vs. IOUT Source


Figure 25. $I_{B}$ vs. $V_{C M}$, Four Temperatures


Figure 26. VOS vs. I IUT


Figure 27. VDROPOUT $\left(V_{\text {OUT }}-(V-)\right)$ vs. IOUT Sink

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 28. $\mathrm{Z}_{\text {OUT }}$ vs. Frequency


Figure 29. Open-Loop Gain and Phase vs. Frequency


Figure 30. Gain Bandwidth Product vs. Temperature


Figure 31. $\mathrm{Z}_{0}$ vs. Frequency


Figure 32. Closed-Loop Gain vs. Frequency


Figure 33. Gain Bandwidth Product vs. Total Supply Voltage

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 34. PSRR vs. Frequency


Figure 35. CMRR vs. Frequency


Figure 36. EMIRR IN+ vs. Frequency ( $P_{R F}$ Is RF Power.)


Figure 37. PSRR vs. Temperature

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Figure 38. CMRR vs. Temperature


Figure 39. Channel Separation vs. Frequency

ADA4510-2

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 40. THD Ratio vs. Output Amplitude


Figure 41. THD Ratio vs. Frequency


Figure 42. THD Ratio vs. Source Resistance


Figure 43. THD Plus Noise (THD + N) Ratio vs. Output Amplitude


Figure 44. THD + N vs. Frequency


Figure 45. Maximum Undistorted Output Swing vs. Frequency

## TYPICAL PERFORMANCE CHARACTERISTICS



TIME ( $1 \mu \mathrm{~s} / \mathrm{DIV}$ )
Figure 46. Positive Step Settling Time to $0.01 \%, V_{\text {OUT }}=5 \mathrm{~V}$


TIME ( $1 \mu \mathrm{~s} / \mathrm{DIV}$ )
Figure 47. Positive Step Settling Time to $0.001 \%, V_{\text {OUT }}=5 \mathrm{~V}$


Figure 48. Positive Step Settling Time to $0.01 \%, V_{\text {OUT }}=10 \mathrm{~V}$


Figure 49. Negative Step Settling Time to $0.01 \%, V_{\text {OUT }}=5 \mathrm{~V}$


TIME (1 $\mu \mathrm{s} / \mathrm{DIV}$ )
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Figure 50. Negative Step Settling Time to $0.001 \%, V_{\text {OUT }}=5 \mathrm{~V}$


TIME ( $1 \mu \mathrm{~s} / \mathrm{DIV}$ )
$\overline{5}$

Figure 51. Negative Step Settling Time to $0.01 \%, V_{\text {OUT }}=10 \mathrm{~V}$

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 52. Positive Step Settling Time to $0.001 \%, V_{\text {OUT }}=10 \mathrm{~V}$


Figure 53. Positive Overload Recovery


Figure 54. Small Signal Transient Response, G $=1$ V/V


Figure 55. Negative Step Settling Time to $0.001 \%, V_{\text {OUT }}=10 \mathrm{~V}$


Figure 56. Negative Overload Recovery


Figure 57. Small Signal Transient Response, G =-1 V/

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 58. Overshoot vs. Capacitance Load, G = 1 V/V


TIME (300ns/DIV)
Figure 59. Large Signal Transient Response, G = 1 V/V


Figure 60. Slew Rate vs. Output Step Voltage


Figure 61. Overshoot vs. Capacitance Load, $\mathbf{G}=-1 \mathrm{~V} / \mathrm{V}$


TIME (300ns/DIV)
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Figure 62. Large Signal Transient Response, G=-1 V/


Figure 63. Slew Rate vs. Temperature

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 64. Input Voltage Noise Spectral Density vs. Frequency


Figure 65.0 .1 Hz to 10 Hz Voltage Noise


Figure 66. Is per Amplifier vs. Supply Voltage at Various Temperatures


Figure 67. Current Noise Spectral Density vs. Frequency


Figure 68. Short-Circuit Output Current vs. Temperature


Figure 69. Is per Amplifier vs. Temperature for Various Supplies

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 70. DC Open-Loop Gain vs. Temperature


Figure 71. No Phase Reversal


Figure 72. DC Open-Loop Gain vs. $R_{L}$

## THEORY OF OPERATION



Figure 73. Simplified Schematic

The ADA4510-2 is a dual-channel, low-power, rail-to-rail input and output, precision CMOS op amp that operates over a wide supply voltage range of 6 V to 40 V . This amplifier uses the Analog Devices DigiTrim technique to achieve a higher degree of precision compared to previous CMOS amplifiers. The DigiTrim technique is a method of trimming the offset voltage and the offset voltage temperature drift of an amplifier after assembly. This technique corrects any offset voltages and drifts caused by mechanical stresses during assembly.

## INPUT AND GAIN STAGES

Figure 73 shows the simplified circuit diagram for the ADA4510-2. The input architecture provides high-impedance, rail-to-rail differential and common-mode input swing, low noise, low input bias current, and low offset voltage.

An integrated EMI filter increases the signal robustness and helps prevent EMI signals from coupling into the amplifier. Depending on the input common-mode voltage, either the negative channel metaloxide semiconductor (NMOS) or the positive channel metal-oxide semiconductor (PMOS) input stage can be active at any time. The low offset voltage and low offset voltage drift specifications are possible by using the DigiTrim technique on both the NMOS and PMOS input stages.

The ADA4510-2 includes circuitry that extends the linear input range, providing higher slew rates than a traditional input differential pair and improving the THD. The wide gain bandwidth product of 10.4 MHz is achieved through internal Miller compensation.

## OUTPUT STAGE

The output of the ADA4510-2 swings rail-to-rail to within 100 mV of either supply rail. A capacitive load compensation block senses the load capacitor and adds additional phase margin, if required, to drive a large capacitor (at least 1 nF ) and maintain amplifier stability.

## EMI REJECTION

High-frequency EMI is a threat to precision amplifier performance in an intended application. Op amps must accurately amplify input signals despite low signal strength and long transmission lines. All operational amplifier pins are susceptible to EMI signals. These high-frequency signals are coupled into an operational amplifier by various means, such as conduction, near-field radiation, or far-field radiation. For example, wires and printed circuit board (PCB) traces act as antennas to pick up high-frequency EMI signals.

Op amps do not amplify EMI or RF signals due to the relatively low bandwidth of the amplifier. However, due to the nonlinearities of the input devices, op amps can rectify these out-of-band signals, which then appear as a DC offset at the output.

The ADA4510-2 is designed with integrated EMI filters at the input stage of the op amp. The EMIRR describes the ability of the ADA4510-2 to perform as intended in the presence of electromagnetic energy. The EMIRR is specified for the noninverting pin in Table 1. A mathematical method of measuring EMIRR is defined as follows:
$E M I R R=20 \log \times\left(\Delta V_{I N_{-}} P E A K / \Delta V_{O S}\right)$
EMIRR performance of ADA4510-2 is shown in Figure 36.

## NO PHASE INVERSION

The ADA4510-2 does not suffer from output voltage phase reversal that occurs in some op amps when the specified input $V_{C M}$ range is exceeded. Output voltage phase reversal causes the output voltage to swing to the opposite rail until the input comes back within the common-mode range. Typically, the inputs of conventional op amps fail to reach or exceed the common-mode limit toward the negative range. Phase-reversal is most often associated with junction field effect transistor (JFET) and/or bipolar field effect transistor (BiFET) amplifiers, but some bipolar single-supply amplifiers are

## THEORY OF OPERATION

also susceptible phase-reversal. The ADA4510-2 guarantees no phase inversion beyond the entire specified input $V_{C M}$ range all the way to the absolute maximum input voltage limit.

## CAPACITIVE LOAD DRIVE CAPABILITY

The ADA4510-2 is stable with any capacitive load up to 1 nF . This is accomplished by dynamically sensing the load-induced output pole and adjusting the compensation at the internal gain node of the amplifier. As the capacitive load increases, the bandwidth will decrease. The phase margin may increase or decrease with different capacitive loads, so there may be overshoot in the transient response for some capacitive loads (see Figure 58 and Figure 61). Coaxial cable less than 1 nF can be driven directly, but, for best pulse fidelity, the cable should be properly terminated by placing a resistor of a value equal to the characteristic impedance of the cable (for example $50 \Omega$ ) in series with the output. The other end of the cable should be terminated with the same value resistor to ground.

Figure 58 and Figure 61 show the overshoot of the ADA4510-2 with various capacitive loads in unity gain and gain of -1 configurations. To further improve the capacitive load drive of the ADA4510-2, an isolation resistor ( $\mathrm{R}_{\text {ISO }}$ ) may be used in series with the output to significantly reduce the overshoot and ringing to stabilize the amplifier.
Table 7. Capacitive Load Drive at Various $R_{I S O}$

| Capacitive Load | 100 pF |  |  | 1000 pF |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{R}_{\text {ISO }}$ | $0 \Omega$ | $24.9 \Omega$ | $49.9 \Omega$ | $0 \Omega$ | $24.9 \Omega$ | $49.9 \Omega$ |
| Positive Overshoot <br> Percent | $42 \%$ | $38 \%$ | $35 \%$ | $68 \%$ | $32 \%$ | $18 \%$ |
| Negative Overshoot <br> Percent | $43 \%$ | $38 \%$ | $30 \%$ | $71 \%$ | $29 \%$ | $19 \%$ |

## APPLICATIONS INFORMATION

## MUX-COMPATIBLE DATA ACQUISITION SYSTEM

Data acquisition in multichannel systems can be accomplished by multiplexing as shown in Figure 74. This technique is very popular in instrumentation, industrial process control, and automated test equipment (ATE), because it reduces the number of components needed to sense multiple sensors, saving significant power, size, and cost.


Figure 74. Multiplexed Data Acquisition System
One risk in designing this system is the possibility of exposing the buffer amplifier to a large differential voltage due to the fast switching from a large positive voltage to a large negative voltage by the mux. If the buffer amplifier is not chosen properly, it may experience a large inrush current that can degrade the performance of the system or, worse, permanently damage the part.
The ADA4510-2 solves this problem using a robust mux-compatible architecture that can tolerate large differential voltages up to the supply rails without the use of differential back-to-back diodes. This significantly reduces inrush current, improves settling and distortion performance without experiencing any input loading effect compared to classic op amps with back-to-back diodes, as shown in Figure 75.


Figure 75. ADA4510-2 Inrush Current Reduction

## Design Example

The circuit shown in Figure 76 is a classic multichannel data acquisition signal chain consisting of a mux, amplifiers, and an ana-log-to-digital converter (ADC). The architecture allows fast sampling of multiple channels using a single ADC, providing low cost and
excellent channel-to-channel matching. Channel-to-channel switching speed is limited by the settling time of the various components following the mux in the signal chain, because the mux can present a full-scale step $\mathrm{V}_{\text {OUT }}$ to the downstream amplifier and the ADC. The components in this circuit have been specifically chosen to minimize settling time and maximize channel-to-channel switching speed.


Figure 76. 16-bit, 8-Channel, Single-ended to Differential, Multiplexed Data Acquisition System

This circuit operates in continuous switching mode. The multiplexer ADG5408 switches continuously with a switching rate that is in sync with the ADC conversion cycle. The signal is buffered by the ADA4510-2 and drives to the AD8475, which attenuates, level shifts, and converts the signal from single-ended to a differential output. An RC filter is used at the input of the ADC to minimize out-of-band noise and attenuate the kickback from the switched capacitor at the ADC input.

To calculate the settling time, the circuit can be divided into parts shown in Figure 77.


Figure 77. Block Diagram for Settling Time Analysis
The entire settling time is then approximated as the RSS of the settling time of each stage.

## APPLICATIONS INFORMATION



Figure 78. Error (LSB) vs. Switching Rate, 8-Channel 10 V Step
Figure 78 shows the error in LSB vs. switching rate for an 8 -channel 10 V step mux data acquisition system. An LSB error <1 is achieved up to 570 kHz switching rate.

## TRANSIMPEDANCE AMPLIFIER

The ADA4510-2 is an excellent choice for low noise transimpedance amplifier (TIA) applications. The low voltage and current noise of the ADA4510-2 maximize signal-to-noise ratio (SNR), and the low $V_{\text {OS }}$ and $I_{B}$ of the ADA4510-2 minimize the $D C$ error at the amplifier output.

Common applications for current-to-voltage conversion include photodiode circuits where the amplifier converts a current emitted by a diode placed at the negative input terminal into an output voltage. Some photodiode applications include fiber optic controls, motion sensors, and barcode readers. The circuit shown in Figure 79 shows one channel of the ADA4510-2 as a current-to-voltage converter with an electrical model of a photodiode.


Figure 79. Equivalent TIA Circuit
Photodiodes operate in either photovoltaic mode (zero bias) or photoconductive mode (with an applied reverse-bias across the diode). Mode selection depends on the speed and dark current requirements of the application and the choice of photodiode. In photovoltaic mode, the dark current is at a minimum and is preferred for low frequency and/or low light level applications (that is, PN photodiodes). Photoconductive mode is better for applications
that require faster and linear responses (that is, PIN photodiodes); however, the tradeoffs include increases in dark and noise currents.
The following transfer function describes the transimpedance gain of Figure 79:
$V_{\text {OUT }}=\frac{I_{D} R_{F}}{1+s C_{F} R_{F}}$
where:
$V_{\text {OUT }}$ is the desired output DC voltage of the op amp.
$I_{D}$ is the output current of the photodiode.
$R_{F}$ is the feedback resistor.
$C_{F}$ is the feedback capacitor.
The parallel combination of $R_{F}$ and $C_{F}$ sets the signal bandwidth.
$s$ is the complex frequency variable $j \omega$.
$j$ is the imaginary unit.
$\omega$ is the angular frequency.
Set $R_{F}$ such that the maximum attainable $V_{\text {OuT }}$ corresponds to the maximum diode I Iout. Because signal levels increase directly with $R_{F}$, while the noise due to $R_{F}$ increases with the square root of the resistor value, employing the full output swing maximizes the SNR.

It is important to distinguish between the transimpedance gain and the loop gain, because the loop gain characteristics determine the net circuit stability. The closed-loop transfer function takes the form shown in the following equation:
$\frac{V_{\text {OUT }}}{V_{I N}}=\frac{A}{1+A \beta}$
where:
$A$ is the open loop gain of the amplifier.
$\beta$ is the feedback network.
$A \beta$ is the loop gain.
In this application $\beta$ is given by the following:
$\beta=\left(\frac{R_{S H}}{R_{S H}+R_{F}}\right) \frac{1+s R_{F} C_{F}}{1+s\left(R_{F} \| R_{S H}\right)\left(C_{I N}+C_{F}\right)}$
where:
$R_{S H}$ is the diode shunt resistance.
$\mathrm{C}_{1 N}$ is the total input capacitance consisting of the sum of the diode shunt capacitance ( $\mathrm{C}_{\mathrm{PD}}$ ), the input capacitance of the amplifier ( $C_{D M}+C_{C M}$ ), and the external stray capacitance.
$C_{I N}, R_{F}, C_{F}$, and $R_{S H}$ produce a zero in the $1 / \beta$ transfer function.
The zero frequency $\left(f_{z}\right)$ is as in the equation that follows:
$f_{Z}=\frac{1}{2 \pi\left(R_{F} \| R_{S H}\right)\left(C_{I N}+C_{F}\right)}$
Because the photodiode shunt resistance $R_{S H} \gg R_{F}$, the circuit behavior is not impacted by the effect of the junction resistance, and $f_{z}$ simplifies to the following:
$f_{Z}=\frac{1}{2 \pi R_{F}\left(C_{I N}+C_{F}\right)}$

## APPLICATIONS INFORMATION

Figure 80 shows the TIA $1 / \beta$ curve superimposed upon the open loop gain of the amplifier. For the system to be stable, the $1 / \beta$ curve must have a slope of less than $20 \mathrm{~dB} /$ decade when it intersects with the open loop response. In Figure 80 the dotted line shows an uncompensated $1 / \beta$ response ( $C_{F}=0 \mathrm{pF}$ ) intersecting with the open loop gain at the frequency ( $\mathrm{f} x$ ) with a slope of $20 \mathrm{~dB} /$ decade which indicates an unstable condition.


Figure 80. Generalized TIA 1/ß and Transfer Function
The instability caused by $\mathrm{C}_{\mathbb{N}}$ can be compensated by adding $\mathrm{C}_{\mathrm{F}}$ to introduce a pole at a frequency equal to or lower than $\mathrm{f}_{\mathrm{x}}$. The pole frequency is as follows:
$f_{P}=\frac{1}{2 \pi R_{F} C_{F}}$
Setting the pole at the $f_{\mathrm{X}}$ frequency maximizes the signal bandwidth with a $45^{\circ}$ phase margin but is marginal for stability, as indicated by the dashed line. Because $f_{x}$ is the geometric mean of $f_{Z}$ and the gain bandwidth product frequency ( $\mathrm{f}_{\mathrm{GBP}}$ ) of the amplifier, calculate $f_{X}$ by the following equation:
$f_{X}=\sqrt{\mathrm{f}_{Z} f_{G B P}}$
Substituting Equation 5 and Equation 6 into Equation 7, the $C_{F}$ value that produces $f_{x}$ follows:

$$
\begin{equation*}
C_{F}=\frac{1+\sqrt{1+8 \pi R_{F} C_{I N} f_{G B P}}}{4 \pi R_{F} f_{G B P}} \tag{8}
\end{equation*}
$$

If $8 \pi \times R_{F} \times C_{I N} \times f_{G B P} \gg 1$, Equation 8 simplifies to the following:
$C_{F}=\sqrt{\frac{C_{I N}}{2 \pi R_{F} f_{G B P}}}$
Adding $\mathrm{C}_{\mathrm{F}}$ also sets the signal bandwidth at $\mathrm{f}_{\mathrm{p}}$. Substitute Equation 9 into Equation 6 and rearrange the equation for the signal bandwidth in terms of $f_{G B P}, R_{F}$, and $C_{\mathbb{N}}$ as follows:
$f_{P}=\sqrt{\frac{f_{G B P}}{2 \pi R_{F} C_{I N}}}$
Notice the attainable signal bandwidth is a function of the time constant $\mathrm{R}_{\mathrm{F}} \mathrm{C}_{\mathbb{N}}$ and the $\mathrm{f}_{\mathrm{GBP}}$ of the amplifier. To maximize the signal bandwidth, choose an op amp with high bandwidth and low input
capacitance, and operate the photodiode in reverse bias to reduce its junction capacitance.

## Design Example

As a design example, Figure 81 shows one channel of the ADA4510-2 configured as a TIA amplifier in a photodiode preamp application. Assuming the photodiode has a $C_{D}$ of 5 pF , an $\mathrm{I}_{\mathrm{D}}$ of $2 \mu \mathrm{~A}$, and the desired full-scale $\mathrm{V}_{\text {OUT }}$ is $100 \mathrm{mV}, R_{F}$ is $49.9 \mathrm{k} \Omega$ according to Equation 1.


Figure 81. Single-Supply TIA Circuit Using the ADA4510-2
The ADA4510-2 input capacitance ( $\mathrm{C}_{\mathrm{CM}}+\mathrm{C}_{\mathrm{DM}}$ ) is 22 pF , so the total input capacitance ( $\mathrm{C}_{\mathbb{N}}$ ) is 27 pF . By substituting $\mathrm{C}_{\mathbb{N}}=27 \mathrm{pF}$, $R_{F}=49.9 \mathrm{k} \Omega$, and $f_{G B P}=10 \mathrm{MHz}$ into Equation 8 and Equation 10, the resulting $C_{F}$ value and the -3 dB signal bandwidth ( $\mathrm{f}_{\mathrm{P}}$ ) are 3.1 pF and 1.1 MHz , respectively.
Figure 82 and Figure 83 show the compensations of the TIA circuit. The system has a bandwidth of 1.1 MHz when it is maximized for a signal bandwidth with $\mathrm{C}_{\mathrm{F}}=3.1 \mathrm{pF}$. Increasing $\mathrm{C}_{\mathrm{F}}$ to 5.5 pF reduces the bandwidth to 579 kHz . However, increasing the $\mathrm{C}_{\mathrm{F}}$ greatly reduces the overshoot (see Figure 84). In practice, an optimum $\mathrm{C}_{\mathrm{F}}$ value is determined experimentally by varying it slightly to optimize the output pulse response.

Use the Analog Devices Analog Photodiode Wizard to design a transimpedance amplifier circuit to interface with a photodiode.

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Figure 82. Compensating the TIA, $C_{F}=3.1 \mathrm{pF}$


Figure 83. Compensating the TIA, $C_{F}=5.5 \mathrm{pF}$


TIME ( $1 \mu \mathrm{~s} / \mathrm{DIV}$ )
®
Figure 84. Pulse Response for Various $C_{F}$

## ACTIVE FILTER



Figure 85. 4-Pole Low Pass Filter with -3dB Bandwidth of 10kHz
Active filters are used to separate signals, passing signals of interest and attenuating signals at unwanted frequencies. For example, low-pass filters are often used as antialiasing filters in data acquisition systems or as noise filters to limit high frequency noise.

The high input impedance, high bandwidth, low input bias current, and DC precision make the ADA4510-2 a good fit for active filter applications. Figure 85 shows the ADA4510-2 in a 4-pole SallenKey Butterworth low-pass filter configuration. The 4-pole low-pass filter has two complex conjugate pole pairs and is implemented by cascading two 2-pole low-pass filters. Section A and Section B are configured as 2 -pole low-pass filters in unity gain. Table 8 shows the quality factor $(\mathrm{Q})$ requirement and pole position associated with each stage of the Butterworth filter. Refer to Chapter 8, Analog Filters, in Linear Circuit Design Handbook, available at www.analog.com/AnalogDialogue, for pole locations on the s plane and Q requirements for filters of a different order.

Table 8. Q Requirements and Pole Positions

| Section | Poles | Q |
| :--- | :--- | :--- |
| A | $-0.9239 \pm j 0.3827$ | 0.5412 |
| B | $-0.3827 \pm j 0.9239$ | 1.3065 |

The Sallen-Key topology is widely used due to its simple design with few circuit elements. This topology provides the user the flexibility of implementing either a low-pass or a high-pass filter by simply interchanging the resistors and capacitors. The ADA4510-2 is configured in unity gain with a corner frequency at 10 kHz . An active filter requires an op amp with a unity-gain bandwidth that is at least 100 times greater than the product of the corner frequency $\left(f_{\mathrm{C}}\right)$ and the Q. The resistors and capacitors are also important in determining the performance over manufacturing tolerances, time, and temperature. At least $1 \%$ or better tolerance resistors and $5 \%$ or better tolerance capacitors are recommended.

Figure 86 shows the frequency response of the low-pass SallenKey filter, where:
$V_{\text {OUT1 }}$ is the output of the first stage.
$V_{\text {OUT2 }}$ is the output of the second stage.
$V_{\text {OUt1 }}$ shows a 40 dB /decade roll-off and $\mathrm{V}_{\text {OUT2 }}$ shows an $80 \mathrm{~dB} /$ decade roll-off. The transition band becomes sharper as the order of the filter increases.

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Figure 86. Low-Pass Filter: Gain vs. Frequency

## FEEDBACK COMPONENTS

When feedback resistors are used to set up gain, care must be taken to ensure that the pole formed by the resistors and the parasitic capacitance at the inverting input does not degrade stability. If the pole formed is near the desired crossover frequency of the amplifier, the stability will be negatively impacted.

In general, if the parasitic pole lies within the closed-loop bandwidth of the amplifier, add a capacitor in parallel with the $R_{F}$ to introduce a zero that has a frequency close to the frequency of the pole to improve stability.

For a more detailed discussion, see the Analog Dialogue article: Truth About Voltage Feedback Resistors.

## PRECISION BUFFER

The overall precision of high-resolution systems with ADCs and digital-to-analog converters (DACs) depends on the accuracy, stability, and drive capability of the voltage reference of the system. Typically, the best performance requires a costly external reference, because on-chip references and buffers often have poor performance or insufficient drive.

With its low noise specs, the ADA4510-2 can be used to preserve the accuracy of the chosen reference for successive approximation register (SAR) ADC reference inputs. The Voltage Reference Design for Precision Successive-Approximation ADCs Analog Dialogue Article details several considerations and how to compute for noise from the reference circuit to ensure that ADC performance is not affected.

DAC outputs that drive real world sensors also depend on the accuracy of the reference voltage. The low $\mathrm{V}_{\mathrm{OS}}, \Delta \mathrm{V}_{\mathrm{OS}} / \Delta \mathrm{T}, \mathrm{I}_{\mathrm{B}}, \mathrm{e}_{\mathrm{n}}$ $p-p$, and very high linearity, in combination with the fast settling time and slew rate, make the ADA4510-2 an ideal fit for an output DAC buffer.

## RECOMMENDED POWER SOLUTION

Analog Devices, Inc. has a wide range of power management products that meet the requirements of most high performance signal chains. For a dual-supply application, the ADA4510-2 may need as high as $\pm 20 \mathrm{~V}$ supply. Low dropout (LDO) linear regulators such as the LT3042 for the positive supply and the LT3093 for the negative supply help improve the PSRR at high frequency and generate a low noise power rail. In addition, if a negative supply is not available, the ADP5070 can generate the negative supply from a positive supply. Table 9 shows the list of the recommended Power Management Devices for ADA4510-2.

Table 9. Recommended Power Management Devices

| Product | Description |
| :--- | :--- |
| ADP5070 | DC-to-dc switching regulator with independent <br> positive and negative outputs <br> LT3032 |
| Dual 150mA positive/negative low noise LDO <br> linear regulator <br> $-20 \mathrm{~V}, 200 \mathrm{~mA}$, ultralow noise, ultrahigh PSRR <br> negative linear regulator <br> $20 \mathrm{~V}, 200 \mathrm{~mA}, ~ u l t r a l o w ~ n o i s e, ~ u l t r a h i g h ~ P S R R ~ R F ~$ |  |
| linear regulator |  |

It is recommended to use a low ESR, $0.1 \mu \mathrm{~F}$ bypass capacitor close to each of the power supply pins of the ADA4510-2 and ground to reduce errors coupling in from the power supplies. For noisy power supplies, place an additional $10 \mu \mathrm{~F}$ capacitor in parallel with the 0.1 $\mu \mathrm{F}$ for better performance.

## LAYOUT GUIDELINES

The ADA4510-2 has extremely high impedance inputs. Shunt impedances from leakage resistance and parasitic capacitance in the PCB layout can severely degrade the performance of the low bias input. Protect against parasitic leakage currents by using guarding techniques to reduce the voltage gradient seen by the input node. Physically, a guard is a low impedance conductor that surrounds a high impedance node and is driven to the voltage of that node. It serves to buffer leakage by diverting the leakage away from the sensitive node and into the low impedance guard. Remove the solder mask from the guard traces to guard against surface leakage due to contamination. Place any input resistors close to the ADA4510-2 inputs to avoid interaction with trace parasitics. If one of the channels is not in use, connect the input to a voltage that is within the linear range of the channel to avoid overdrive conditions that can interfere with other channels. Leave the output unconnected. Place decoupling capacitors, such as $0.1 \mu \mathrm{~F}$, near the ADA4510-2. Larger capacitors, such as $10 \mu \mathrm{~F}$, can be used farther away from the op amp.

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 87. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-8)
Dimensions show in millimeters and (inches)
Updated: July 24, 2023
ORDERING GUIDE

| Model $^{1}$ | Temperature Range | Package Description | Packing Quantity | Package Option |
| :--- | :--- | :--- | :--- | :--- |
| ADA4510-2ARZ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead Standard Small Outline Package [SOIC_N] |  | R-8 |
| ADA4510-2ARZ-R7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | $8-$ Lead Standard Small Outline Package [SOIC_N] | Reel, 1000 | R-8 |
| ADA4510-2ARZ-RL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 -Lead Standard Small Outline Package [SOIC_N] | Reel, 2500 | R-8 |

1 Z = RoHS Compliant Part.

## EVALUATION BOARDS

| Model $^{1}$ | Description |
| :--- | :--- |
| EVAL-ADA4510-2ARZ | Evaluation Board |
| 1 Z $=$ RoHS Compliant Part. |  |

